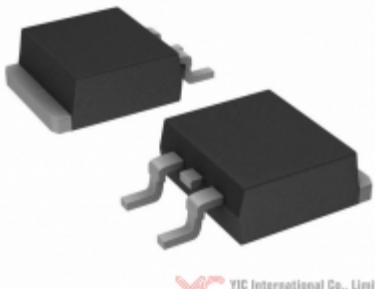









	<h2 style="color: #E67E22;">IPB100N10S3-05</h2>	
	Hersteller-Teilenummer:	IPB100N10S3-05
	Hersteller / Marke:	International Rectifier (Infineon Technologies)
	Teil der Beschreibung:	IPB100N10S3-05 Infineon Technologies
	Datenblätter:	 IPB100N10S3-05.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 8840 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	IPB100N10S3-05
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	IPB100N10S3-05 Infineon Technologies
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	8840 pcs Stock
Serie	OptiMOS™
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	PG-TO263-3-2
Verlustleistung (max)	300W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	100A (Tc)
Rds On (Max) @ Id, Vgs	4.8 mOhm @ 100A, 10V
VGS (th) (Max) @ Id	4V @ 240µA
Gate Charge (Qg) (Max) @ Vgs	176nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	11570pF @ 25V
Verpackung	Original-Reel®

IPB100N10S3-05 ist neu im Original, Suche IPB100N10S3-05 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPB100N10S3-05 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPB100N10S3-05: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IPB100P03P3L-04 D2-PAK</p>	 <p>IPB100N08S2L07ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 75V 100A TO263-3</p>	 <p>IPB100N12S305ATMA1 International Rectifier (Infineon Technologies) N-CHANNEL_100+</p>	 <p>IPB107N20N3 G International Rectifier (Infineon Technologies) IPB107N20N3 G Infineon Technologies</p>
 <p>IPB100N10S305ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 100V 100A TO263-3</p>	 <p>IPB100N08S2L-07 IPB100N08S2L-07 </p>	 <p>IPB100N08S207ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 75V 100A TO263-3</p>	 <p>IPB100N06S3L-04 International Rectifier (Infineon Technologies) MOSFET N-CH 55V 100A TO-263</p>

heiße Teile

Mehr

⊗ IPB093N04LG	↔ IPB096N03L	⇒ IPB096N03LG	D IPB097N08N3	↔ IPB097N08N3G
⊣ IPB09N03	⊗ IPB09N03LA	D IPB09N03LAG	⇒ IPB09N03LAT	↔ IPB100N04S2-04
⊗ IPB100N04S2L-03	⊣ IPB100N04S3	⊗ IPB100N04S3-03	↔ IPB100N04S3-03M	↔ IPB100N04S4-02D
D IPB100N04S4-03D	⊗ IPB100N04S4-H2	⊣ IPB100N06S2-05	⊗ IPB100N06S2L-05	↔ IPB100N06S3-03
⇒ IPB100N06S3-04	↔ IPB100N06S3L-03	⊗ IPB100N06S3L-04	⊣ IPB100N08S2-07	↔ IPB100N08S2L-07
↔ IPB107N20N3G	⇒ IPB10N03L	D IPB10N03LB	⊗ IPB10N03LBG	⊣ IPB110N06L
⊗ IPB110N06LG	D IPB114N03L	⇒ IPB114N03LG	↔ IPB11N03LAG	↔ IPB11N60S5
⊣ IPB120N04S3-02	⊗ IPB120N04S4-01	↔ IPB120N04S4-02	⇒ IPB120N06NG	↔ IPB120N06S4
⊗ IPB120N06S4-02	⊣ IPB120N06S4-03	⊗ IPB120N06S4-H1	D IPB120P04L03	↔ IPB120P04P4L-03
↔ IPB123N10N3	⊗ IPB123N10N3G	⊣ IPB12CN10LG	⊗ IPB12CN10NG	↔ IPB12CNE8NG

Contact us: Info@Y-IC.com

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